#### NOT RECOMMENDED FOR NEW DESIGN **USE DMP3036SFV**



DMP3008SFG

#### 30V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX T <sub>A</sub> = +25°C
	17mΩ @ V <sub>GS</sub> = -10V	-8.6A
-30V	$25\text{m}\Omega$ @ $V_{GS} = -4.5V$	-7.1A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

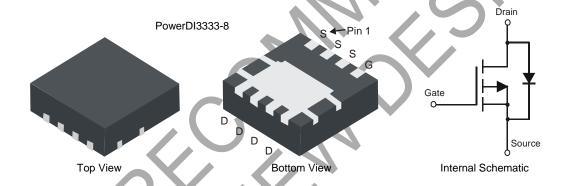
- Backlighting
- Power Management Functions
- **DC-DC Converters**

### **Features and Benefits**

- Low R<sub>DS(ON)</sub> Ensures On State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher **Density End Products**
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: PowerDI®3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)



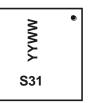
#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3008SFG-7	PowerDI3333-8	2000/Tape & Reel
DMP3008SFG-13	PowerDI3333-8	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



S31 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)



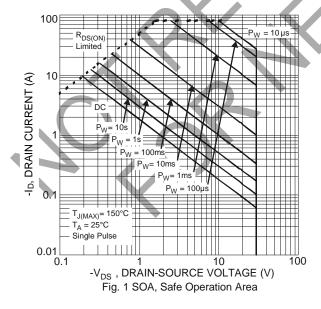
# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

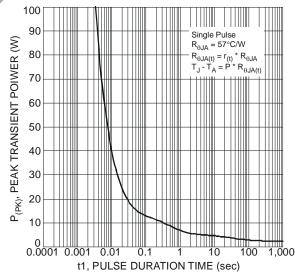
Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-30	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
Continuous Dusin Compart (Nata C) V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-8.6 -7.0	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-11.7 -9.3	А
Outliness Proje Outlines (Alace O) V		$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-7.1 -5.6	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = -4.5V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-9.6 -7.6	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-80	Α		
Maximum Continuous Body Diode Forward Current (Note 6)			I <sub>S</sub>	-3.0	Α

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

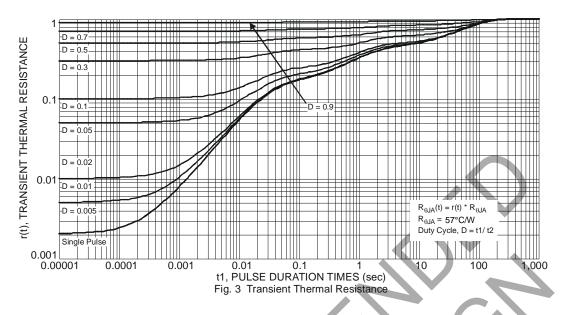
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P <sub>D</sub>	0.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	140	°C/W
Thermal Resistance, Junction to Ambient (Note 3)	t<10s	$R_{\theta JA}$	72	°C/W
Total Power Dissipation (Note 6)		PD	2.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State		57	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	30	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta JC}$	7.1	°C/W
Operating and Storage Temperature Range		$T_{J}, T_{STG}$	-55 to +150	°C

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:









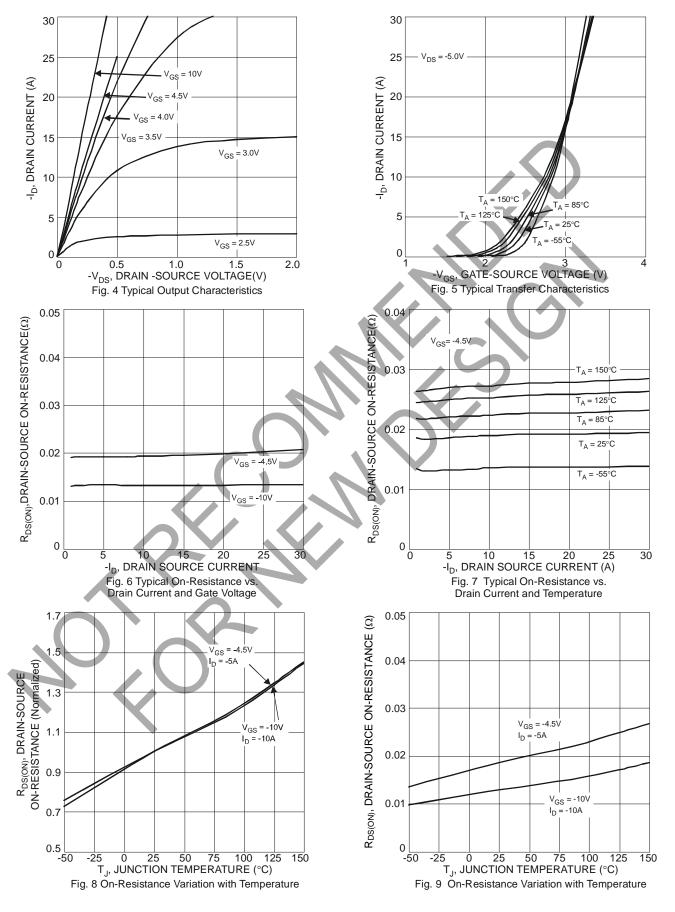
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	_		V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS		_	-1.0	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(TH)}$	-4.1	-1.6	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance			12.5	17	mΩ	$V_{GS} = -10V, I_D = -10A$	
Static Dialif-Source Off-Resistance	R <sub>DS(ON)</sub>		18.5	25	1112.2	$V_{GS} = -4.5V, I_D = -10A$	
Forward Transfer Admittance	Y <sub>fs</sub>		13	_	S	$V_{DS} = -15V, I_{D} = -10A$	
Diode Forward Voltage	V <sub>SD</sub>		-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	2230				
Output Capacitance	Coss		328	_	pF	$V_{DS} = -15V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss		294	_		1 = 1.0IVII 12	
Gate Resistance	Rg	_	6.4	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	47	_			
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	23	_	]		
Gate-Source Charge	$Q_{gs}$	_	9.4	_	nC	$V_{DS} = -15V, I_{D} = -10A$	
Gate-Drain Charge	$Q_{gd}$	_	5.6	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	10.5	_			
Turn-On Rise Time	t <sub>R</sub>	_	8.5	_	ns	Vac = 10V Vac = 15V B = 60	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	90	_	115	$V_{GS} = -10V, V_{DS} = -15V, R_g = 6\Omega$	
Turn-Off Fall Time	t <sub>F</sub>		40	_			

Notes: 7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.







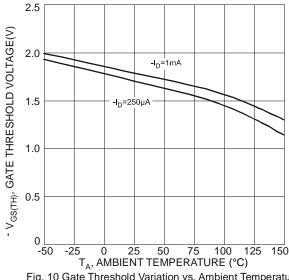
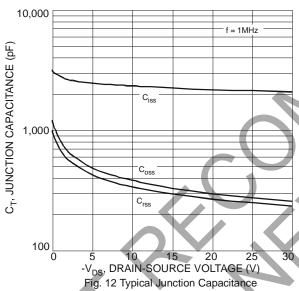
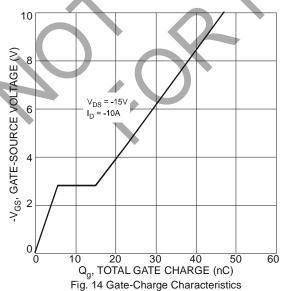


Fig. 10 Gate Threshold Variation vs. Ambient Temperature





20 18 16 -I<sub>S</sub>, SOURCE CURRENT (A) T<sub>A</sub>= 25°C 10 0 0.6 0.8 1.0 -V<sub>SD</sub>, SOURCE-DRAIN VOLTAGE (V) Fig. 11 Diode Forward Voltage vs. Current 0.4 1.2

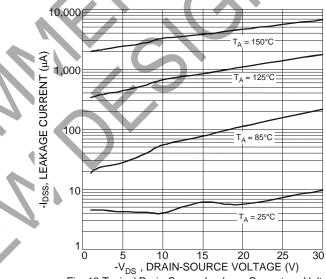


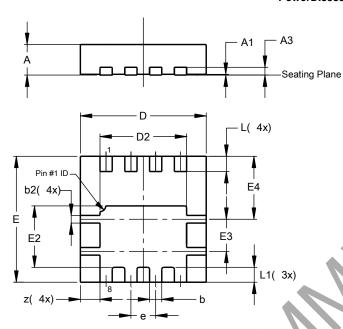
Fig. 13 Typical Drain-Source Leakage Current vs. Voltage



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8

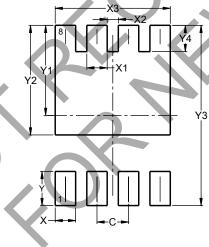


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
<b>A</b> 1	0.00	0.05	0.02		
A3	_	_	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	_	_	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

# PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.370
Υ	0.700
Y1	1.850
Y2	2.250
Y3	3.700
V4	0.540



# NOT RECOMMENDED FOR NEW DESIGN USE <u>DMP3036SFV</u>

DMP3008SFG

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